INTEGRATED CIRCUITS



Product specification IC05 Data Handbook

1991 Feb 08



Philips Semiconductors

74ALS646/74ALS646-1

74ALS648/74ALS648-1

Transceiver/register

74ALS646/646-1 74ALS648/648-1 Octal transceiver/register, non-inverting (3-State) Octal transceiver/register, inverting (3-State)

FEATURES

- Combines 74ALS245 and two 74ALS374 type functions in one chip
- Independent registers for A and B buses
- Multiplexed real-time and stored data
- Choice of non-inverting and inverting data paths
- 3-State outputs
- \bullet The -1 version sink 48mA I_OL within the ±5% V_CC range

DESCRIPTION

The 74ALS646/74ALS646-1 and 74ALS648/74ALS648-1 transceivers/registers consist of bus transceiver circuits with 3-State outputs, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes High. Output enable (\overline{OE}) and direction (DIR) and select (SAB, SBA) pins are provided for bus management.

The 74ALS646-1 and 74ALS648-1 will sink 48mA if the V_{CC} is limited to 5.0V $\pm 0.25V.$

INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

ТҮРЕ	TYPICAL f _{MAX}	TYPICAL SUPPLY CURRENT (TOTAL)		
74ALS646/646-1	140MHz	48mA		
74ALS648/648-1	140MHz	54mA		

ORDERING INFORMATION

	ORDER CODE			
DESCRIPTION	COMMERCIAL RANGE V _{CC} = 5V ±10%, T _{amb} = 0°C to +70°C	DRAWING NUMBER		
24-pin plastic DIP	74ALS646N, 74ALS646-1N, 74ALS648N, 74ALS648-1N	SOT222-1		
24-pin plastic SOL	74ALS646D, 74ALS646-1D, 74ALS648D, 74ALS648-1D	SOT137-1		

PINS	DESCRIPTION	74ALS (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
A0 – A7	A inputs	1.0/1.0	20μΑ/0.1mA
B0 – B7	B inputs	1.0/1.0	20µA/0.1mA
CPAB	A-to-B clock input	1.0/1.0	20µA/0.1mA
СРВА	B-to-A clock input	1.0/1.0	20µA/0.1mA
SAB	A-to-B select input	1.0/1.0	20µA/0.1mA
SBA	B-to-A select input	1.0/1.0	20µA/0.1mA
DIR	Data flow directional control input	1.0/1.0	20µA/0.1mA
ŌĒ	Output enable input	1.0/1.0	20µA/0.1mA
A0 – A7, B0 – B7	Data outputs	750/240	15mA/24mA
A0 – A7, B0 – B7	Data outputs (-1 version)	750/480	15mA/48mA

NOTE: One (1.0) ALS unit load is defined as: 20µA in the High state and 0.1mA in the Low state.

74ALS646/74ALS646-1 74ALS648/74ALS648-1

PIN CONFIGURATION - 74ALS646/646-1



LOGIC SYMBOL - 74ALS646/646-1



IEC/IEEE SYMBOL - 74ALS646/646-1



PIN CONFIGURATION - 74ALS648/648-1



LOGIC SYMBOL - 74ALS648/648-1



IEC/IEEE SYMBOL - 74ALS648/648-1



74ALS646/74ALS646-1 74ALS648/74ALS648-1

BUS MANAGEMENT FUNCTIONS

The following examples demonstrate the four fundamental bus-management functions that can be performed with the 74ALS646/646-1 and 74ALS648/648-1.

The select pins determine whether data is stored or transferred through the device in real time.

The DIR determines which bus will receive data when the OE pin is Low.



74ALS646/74ALS646-1 74ALS648/74ALS648-1

LOGIC SYMBOL - 74ALS646/646-1



LOGIC SYMBOL - 74ALS648/648-1



FUNCTION TABLE

		INP	UTS			DAT	a I/o	OPERATING MODE		
OE	DIR	СРАВ	СРВА	SAB	SBA	An Bn		74ALS646/74ALS646-1	74ALS648/74ALS648-1	
Х	Х	\uparrow	Х	Х	Х	Input	Unspecified*	Store A, B unspecified*	Store A, B unspecified*	
Х	Х	Х	\uparrow	Х	Х	Unspecified*	Input	Store B, A unspecified*	Store B, A unspecified*	
Н	Х	\uparrow	\uparrow	Х	Х	Input	Input	Store A and B data	Store A and B data	
Н	Х	H or L	H or L	Х	Х	Input	Input	Isolation, hold storage	Isolation, hold storage	
L	L	Х	Х	Х	L	Output	Input	Real time B data to A bus	Real time \overline{B} data to A bus	
L	L	Х	H or L	Х	Н	Output	Input	Stored B data to A bus	Stored \overline{B} data to A bus	
L	Н	Х	Х	L	Х	Input	Output	Real time A data to B bus	Real time \overline{A} data to B bus	
L	Н	H or L	Х	Н	Х	Input	Output	Stored A data to B bus	Stored \overline{A} data to B bus	

NOTES:

H = High voltage level L = Low voltage level

Х Don't care =

The data output function may be enabled or disabled by various signals at the \overline{OE} and DIR inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every Low-to-High transition of the clock. =

 \uparrow = Low-to-High clock transition

74ALS646/74ALS646-1 74ALS648/74ALS648-1

ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limit set forth in this table may impair the useful life of the device.

Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER		RATING	UNIT
V _{CC}	Supply voltage		-0.5 to +7.0	V
V _{IN}	Input voltage		-0.5 to +7.0	V
I _{IN}	Input current		-30 to +5	mA
V _{OUT}	Voltage applied to output in High output state	–0.5 to V_{CC}	V	
	Current applied to output in Low output state	48	mA	
IOUT		96	mA	
T _{amb}	Operating free-air temperature range	0 to +70	°C	
T _{stg}	Storage temperature range		-65 to +150	°C

RECOMMENDED OPERATING CONDITIONS

CYMDOL	PARAMETER						
SYMBOL			MIN	NOM	MAX	UNIT	
V _{CC}	Supply voltage	Supply voltage					
V _{IH}	High-level input voltage	2.0			V		
V _{IL}	Low-level input voltage			0.8	V		
I _{IK}	Input clamp current				-18	mA	
I _{OH}	High-level output current	-			-15	mA	
		All versions			24	mA	
I _{OL}	Low-level output current	-1 version			48 ¹	mA	
T _{amb}	Operating free-air temperature range	0		+70	°C		

NOTE:

1. The 48mA limit applies only under the condition of V_CC = 5.0V $\pm 5\%.$

74ALS646/74ALS646-1 74ALS648/74ALS648-1

DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

CVMDO:	DADAMETE		TERT OCHIDIT				UNIT	
SYMBOL	PARAMETE	:K	TEST CONDITI	MIN	TYP ²	MAX		
			V _{CC} ±10%, V _{IL} = MAX,	I _{OH} = -0.4mA	$V_{CC} - 2$			V
V _{ОН}	High-level output voltage		V _{IH} = MIN	I _{OH} = -3mA	2.4	3.2		V
° OH	g			I _{OH} = -15mA	2.0			V
		Allycomicno	$V_{CC} = MIN, V_{IL} = MAX,$	I _{OL} = 12mA		0.25	0.40	V
Voi	V _{OL} Low-level output voltage	All versions	V _{IH} = MIN	I _{OL} = 24mA		0.35	0.50	V
	-1 versions	$V_{CC} = 4.75V, V_{IL} = MAX, V_{IH} = MIN$	I _{OL} = 48mA		0.35	0.50	V	
V _{IK}	Input clamp voltage	•	$V_{CC} = MIN, I_I = I_{IK}$		-0.73	-1.5	V	
	Input current at maxi-	control inputs	$V_{CC} = MAX, V_1 = 7.0V$				0.1	mA
łı	mum input voltage	A or B ports	$V_{CC} = MAX, V_I = 5.5V$				0.1	mA
I _{IH}	High-level input current ³		$V_{CC} = MAX, V_I = 2.7V$				20	μA
Ι _{ΙL}	Low-level input current ³		$V_{CC} = MAX, V_I = 0.4V$				-0.1	mA
Ι _Ο	Output current ⁴		V_{CC} = MAX, V_{O} = 2.25V		-30		-112	mA
		I _{CCH}				40	57	mA
I _{CC}	I _{CC} Supply current (total)		V _{CC} = MAX			53	78	mA
		I _{CCZ}			51	72	mA	

NOTES:

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

2. All typical values are at $V_{CC} = 5V$, $T_{amb} = 25^{\circ}C$. 3. For I/O ports, the parameter I_{IH} and I_{IL} include the off-state current.

4. The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

AC ELECTRICAL CHARACTERISTICS FOR 74ALS646/74ALS646-1

			LIM		
SYMBOL	PARAMETER	TEST CONDITION	T _{amb} = 0°C V _{CC} = +5. C _L = 50pF,	UNIT	
			MIN	MAX	
f _{max}	Maximum clock frequency	Waveform 1	100		MHz
t _{PLH} t _{PHL}	Propagation delay CPBA to An, CPAB to Bn	Waveform 1	5.0 6.0	13.0 13.0	ns
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	Waveform 2, 3	2.0 3.0	8.0 9.0	ns
t _{PLH} t _{PHL}	Propagation delay SBA to An or SAB to Bn (A or B Low)	Waveform 2, 3	5.0 5.0	13.0 11.0	ns
t _{PLH} t _{PHL}	Propagation delay SBA to An or SAB to Bn (A or B High)	Waveform 2, 3	5.0 5.0	11.0 11.0	ns
t _{PZH} t _{PZL}	Output enable time OE to An or Bn	Waveform 5 Waveform 6	3.0 5.0	9.0 11.0	ns
t _{PHZ} t _{PLZ}	Output disable time OE to An or Bn	Waveform 5 Waveform 6	2.0 3.0	8.0 10.0	ns
t _{PZH} t _{PZL}	Output enable time DIR to An or Bn	Waveform 5 Waveform 6	2.0 5.0	10.0 12.0	ns
t _{PHZ} t _{PLZ}	Output disable time DIR to An or Bn	Waveform 5 Waveform 6	2.0 3.0	10.0 13.0	ns

74ALS646/74ALS646-1 74ALS648/74ALS648-1

AC ELECTRICAL CHARACTERISTICS FOR 74ALS648/74ALS648-1

			LIM	ITS		
SYMBOL	PARAMETER	TEST CONDITION	T _{amb} = 0°C V _{CC} = +5. C _L = 50pF,			
			MIN	MAX	1	
f _{max}	Maximum clock frequency	Waveform 1	100		MHz	
t _{PLH} t _{PHL}	Propagation delay CPBA to An, CPAB to Bn	Waveform 1	5.0 6.0	13.0 13.0	ns	
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	Waveform 2, 3	1.0 3.0	7.0 9.0	ns	
t _{PLH} t _{PHL}	Propagation delay SBA to An or SAB to Bn (A or B Low)	Waveform 2, 3	5.0 5.0	13.0 11.0	ns	
t _{PLH} t _{PHL}	Propagation delay SBA to An or SAB to Bn (A or B High)	Waveform 2, 3	4.0 5.0	11.0 11.0	ns	
t _{PZH} t _{PZL}	Output enable time OE to An or Bn	Waveform 5 Waveform 6	2.0 4.0	8.0 13.0	ns	
t _{PHZ} t _{PLZ}	Output disable time OE to An or Bn	Waveform 5 Waveform 6	1.0 2.0	8.0 10.0	ns	
t _{PZH} t _{PZL}	Output enable time DIR to An or Bn	Waveform 5 Waveform 6	3.0 5.0	10.0 12.0	ns	
t _{PHZ} t _{PLZ}	Output disable time DIR to An or Bn	Waveform 5 Waveform 6	2.0 2.0	11.0 11.0	ns	

AC SETUP REQUIREMENTS

			LIM		
SYMBOL	PARAMETER	TEST CONDITION	T _{amb} = 0°C V _{CC} = +5. C _L = 50pF,	UNIT	
t _{su} (H) t _{su} (L)	Setup time, High or Low An or Bn to CPAB or CPBA	Waveform 4	5.0 5.0		ns
t _h (H) t _h (L)	Hold time, High or Low An or Bn to CPAB or CPBA	Waveform 4	0.0 1.0		ns
t _w (H) t _w (L)	Pulse width, High or Low CPAB or CPBA	Waveform 1	6.0 4.0		ns

74ALS646/74ALS646-1 74ALS648/74ALS648-1

AC WAVEFORMS

For all waveforms, $V_M = 1.3V$.

The shaded areas indicate when the input is permitted to change for predictable output performance.



Waveform 1. Propagation Delay for Clock Input to Output, Clock Pulse Width, and Maximum Clock Frequency



Waveform 3. Propagation Delay for An to Bn or Bn to An and SAB or SBA to An or Bn



Waveform 5. 3-State Output Enable Time to High Level and Output Disable Time from High Level



Waveform 2. Propagation Delay for An to Bn or Bn to An and SAB or SBA to An or Bn



Waveform 4. Data Setup Time and Hold Times



Waveform 6. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

74ALS646/74ALS646-1 74ALS648/74ALS648-1

TEST CIRCUIT AND WAVEFORMS



74ALS646/74ALS646-1 74ALS648/74ALS648-1



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	с	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	М _Н	w	Z ⁽¹⁾ max.
mm	4.70	0.38	3.94	1.63 1.14	0.56 0.43	0.36 0.25	31.9 31.5	6.73 6.48	2.54	7.62	3.51 3.05	8.13 7.62	10.03 7.62	0.25	2.05
inches	0.185	0.015	0.155	0.064 0.045	0.022 0.017	0.014 0.010	1.256 1.240	0.265 0.255	0.100	0.300	0.138 0.120	0.32 0.30	0.395 0.300	0.01	0.081

Note

1. Plastic or metal protrusions of 0.01 inches maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1550E DATE
SOT222-1		MS-001AF				95-03-11

74ALS646/74ALS646-1 74ALS648/74ALS648-1



74ALS646/74ALS646-1 74ALS648/74ALS648-1

DEFINITIONS		
Data Sheet Identification	Product Status	Definition
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
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